

SPST CMOS ANALOG SWITCHES

FEATURES

- 2-V to 12-V Single-Supply Operation
- Specified ON-State Resistance:
 - 15 Ω Max With 12-V Supply
 - 20 Ω Max With 5-V Supply
 - 50 Ω Max With 3.3-V Supply
- Specified Low OFF-Leakage Currents:
 - 1 nA at 25°C
 - 10 nA at 85°C
- Specified Low ON-Leakage Currents:
 - 1 nA at 25°C
 - 10 nA at 85°C
- Low Charge Injection: 11.5 pC (12-V Supply)
- Fast Switching Speed:
 - $t_{ON} = 80$ ns, $t_{OFF} = 50$ ns (12-V Supply)
- Break-Before-Make Operation ($t_{ON} > t_{OFF}$)
- TTL/CMOS-Logic Compatible With 5-V Supply

DESCRIPTION/ORDERING INFORMATION

The TS12A4514/TS12A4515 are single pole/single throw (SPST), low-voltage, single-supply CMOS analog switches, with very low switch ON-state resistance. The TS12A4514 is normally open (NO). The TS12A4515 is normally closed (NC).

These CMOS switches can operate continuously with a single supply between 2 V and 12 V. Each switch can handle rail-to-rail analog signals. The OFF-leakage current maximum is only 1 nA at 25°C or 10 nA at 85°C.

All digital inputs have 0.8-V to 2.4-V logic thresholds, ensuring TTL/CMOS-logic compatibility when using a 5-V supply.

For pin-compatible parts for use with dual supplies, see the TS12A4516/TS12A4517.

ORDERING INFORMATION

T_A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
–40°C to 85°C	PDIP – P	Reel of 1000	TS12A4514P	TS12A4514P
	SOIC – D	Reel of 1500	TS12A4514D	YD514
		Reel of 2500	TS12A4514DR	
	SOP (SOT-23) – DBV	Reel of 3000	TS12A4514DBVR	9CJ_
	PDIP – P	Reel of 1000	TS12A4515P	TS12A4515P
	SOIC – D	Reel of 1500	TS12A4515D	YD515
		Reel of 2500	TS12A4515DR	
	SOP (SOT-23) – DBV	Reel of 3000	TS12A4515DBVR	9CK_

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

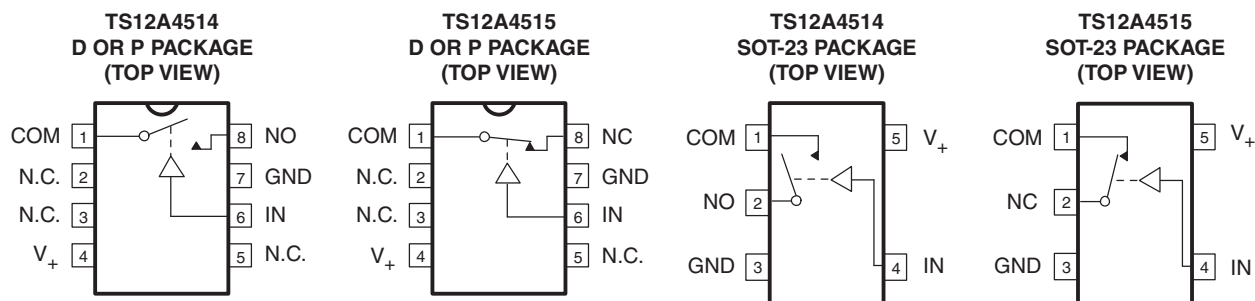
(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(3) DBV: The last character designates assembly/test Site



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PIN CONFIGURATIONS



INPUT	SWITCH STATE	
	TS12A4514	TS12A4515
LOW	OFF	ON
HIGH	ON	OFF

MARKING INFORMATION (SOTs only)	
	LOT SPECIFIC CODE
	AE = TS12A4514
	AF = TS12A4515

N.C. – Not internally connected

NO – Normally open

NC – Normally closed

Absolute Minimum and Maximum Ratings⁽¹⁾⁽²⁾

voltages referenced to GND

		MIN	MAX	UNIT
V ₊	Supply voltage range ⁽³⁾	–0.3	13	V
V _{NC} V _{NO} V _{COM}	Analog voltage range ⁽⁴⁾	–0.3	V ₊ + 0.3 or ±20 mA	V
	Continuous current into any terminal		±20	mA
	Peak current, NO or COM (pulsed at 1 ms, 10% duty cycle)		±30	mA
	ESD per method 3015.7		>2000	V
T _A	Continuous power dissipation (T _A = 70°C)	8-pin plastic DIP (derate 9.09 mW/°C above 70°C)		727
		8-pin SOIC (derate 5.88 mW/°C above 70°C)		471
		5-pin SOT-23 (derate 7.1 mW/°C above 70°C)		571
				mW
T _A	Operating temperature range	–40	85	°C
T _{stg}	Storage temperature range	–65	150	°C
	Lead temperature (soldering, 10 s)		300	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) Voltages exceeding V₊ or GND on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Electrical Characteristics for 5-V Supply⁽¹⁾

 $V_+ = 4.5 \text{ V to } 5.5 \text{ V}$, $V_{INH} = 2.4 \text{ V}$, $V_{INL} = 0.8 \text{ V}$, $T_A = -40^\circ\text{C to } 85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	MIN	TYP ⁽²⁾	MAX	UNIT
Analog Switch							
Analog signal range	V _{COM} , V _{NO} , V _{NC}			0		V ₊	V
ON-state resistance	r _{on}	V ₊ = 4.5 V, V _{COM} = 3.5 V, I _{COM} = 1 mA	25°C		9.5	15	Ω
			Full			20	
ON-state resistance flatness	r _{on(flat)}	V _{COM} = 1 V, 2 V, 3 V, I _{COM} = 1 mA	25°C		1	3	Ω
			Full			4	
NO, NC OFF leakage current ⁽³⁾	I _{NO(OFF)} , I _{NC(OFF)}	V ₊ = 5.5 V, V _{COM} = 1 V, V _{NO} or V _{NC} = 4.5 V	25°C			1	nA
			Full			10	
COM OFF leakage current ⁽³⁾	I _{COM(OFF)}	V ₊ = 5.5 V, V _{COM} = 1 V, V _{NO} or V _{NC} = 4.5 V	25°C			1	nA
			Full			10	
COM ON leakage current ⁽³⁾	I _{COM(ON)}	V ₊ = 5.5 V, V _{COM} = 4.5 V, V _{NO} or V _{NC} = 4.5 V	25°C			1	nA
			Full			10	
Digital Control Input (IN)							
Input logic high	V _{IH}		Full	2.4		V ₊	V
Input logic low	V _{IL}		Full	0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _{IN} = V ₊ , 0 V	Full			0.01	μA
Dynamic							
Turn-on time	t _{ON}	see Figure 2	25°C		32	100	ns
			Full			125	
Turn-off time	t _{OFF}	see Figure 2	25°C		25	50	ns
			Full			60	
Charge injection ⁽⁴⁾	Q _C	C _L = 1 nF, V _{NO} = 0 V, R _S = 0 Ω, See Figure 1	25°C		–3		pC
NO, NC OFF capacitance	C _{NO(OFF)} , C _{NC(OFF)}	f = 1 MHz, See Figure 4	25°C		7.5		pF
COM OFF capacitance	C _{COM(OFF)}	f = 1 MHz, See Figure 4	25°C		7.5		pF
COM ON capacitance	C _{COM(ON)}	f = 1 MHz, See Figure 4	25°C		19		pF
Digital input capacitance	C _I	V _{IN} = V ₊ , 0 V	25°C		1.5		pF
Bandwidth	BW	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C		475		MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C		–94		dB
Total harmonic distortion	THD	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C		0.08		%
Supply							
V ₊ supply current	I ₊	V _{IN} = 0 V or V ₊	25°C			0.05	μA
			Full			0.1	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(2) Typical values are at $T_A = 25^\circ\text{C}$.

(3) Leakage parameters are 100% tested at maximum-rated hot operating temperature, and are ensured by correlation at 25°C .

(4) Specified by design, not production tested

Electrical Characteristics for 12-V Supply⁽¹⁾
 $V_+ = 11.4\text{ V to }12.6\text{ V}$, $V_{INH} = 5\text{ V}$, $V_{INL} = 0.8\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	MIN	TYP ⁽²⁾	MAX	UNIT
Analog Switch							
Analog signal range	V _{COM} , V _{NO} , V _{NC}			0		V ₊	V
ON-state resistance	r _{on}	V ₊ = 11.4 V, V _{COM} = 10 V, I _{COM} = 1 mA	25°C	6.5	10		Ω
			Full		15		
ON-state resistance flatness	r _{on(flat)}	V ₊ = 11.4 V, V _{COM} = 2 V, 5 V, 10 V, I _{COM} = 1 mA	25°C	1.5	3		Ω
			Full		4		
NO, NC OFF leakage current ⁽³⁾	I _{NO(OFF)} , I _{NC(OFF)}	V ₊ = 12.6 V, V _{COM} = 1 V, V _{NO} or V _{NC} = 10 V	25°C		1		nA
			Full		10		
COM OFF leakage current ⁽³⁾	I _{COM(OFF)}	V ₊ = 12.6 V, V _{COM} = 1 V, V _{NO} or V _{NC} = 10 V	25°C		1		nA
			Full		10		
COM ON leakage current ⁽³⁾	I _{COM(ON)}	V ₊ = 12.6 V, V _{COM} = 10 V, V _{NO} or V _{NC} = 10 V	25°C		1		nA
			Full		10		
Digital Control Input (IN)							
Input logic high	V _{IH}		Full	5		V ₊	V
Input logic low	V _{IL}		Full	0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _{IN} = V ₊ , 0 V	Full			0.01	μA
Dynamic							
Turn-on time	t _{ON}	See Figure 2	25°C	22	75		ns
			Full		80		
Turn-off time	t _{OFF}	See Figure 2	25°C	20	45		ns
			Full		50		
Charge injection ⁽⁴⁾	Q _C	C _L = 1 nF, V _{NO} = 0 V, R _S = 0 Ω, See Figure 1	25°C	-11.5			pC
NO, NC OFF capacitance	C _{NO(OFF)} C _{NC(OFF)}	f = 1 MHz, See Figure 4	25°C	7.5			pF
COM OFF capacitance	C _{COM(OFF)}	f = 1 MHz, See Figure 4	25°C	7.5			pF
COM ON capacitance	C _{COM(ON)}	f = 1 MHz, See Figure 4	25°C	21.5			pF
Digital input capacitance	C _I	V _{IN} = V ₊ , 0 V	25°C	1.5			pF
Bandwidth	BW	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	520			MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	-95			dB
Total harmonic distortion	THD	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	0.07			%
Supply							
V ₊ supply current	I ₊	V _{IN} = 0 V or V ₊	25°C		0.05		μA
			Full		0.2		

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(2) Typical values are at $T_A = 25^\circ\text{C}$.(3) Leakage parameters are 100% tested at maximum-rated hot operating temperature, and are ensured by correlation at 25°C .

(4) Specified by design, not production tested

Electrical Characteristics for 3-V Supply⁽¹⁾

 $V_+ = 3\text{ V to }3.6\text{ V}$, $T_A = -40^\circ\text{C to }85^\circ\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	T _A	MIN	TYP ⁽²⁾	MAX	UNIT
Analog Switch							
Analog signal range	V _{COM} , V _{NO} , V _{NC}			0		V ₊	V
ON-state resistance	r _{on}	V ₊ = 3 V, V _{COM} = 1.5 V, I _{NO} = 1 mA,	25°C	18.5	40		Ω
			Full		50		
ON-state resistance flatness	r _{on(flat)}	V ₊ = 3 V, V _{COM} = 1 V, 1.5 V, 2 V, I _{COM} = 1 mA	25°C	1	3		Ω
			Full		4		
NO, NC OFF leakage current ⁽³⁾	I _{NO(OFF)} , I _{NC(OFF)}	V ₊ = 3.6 V, V _{COM} = 1 V, V _{NO} or V _{NC} = 3 V	25°C		1		nA
			Full		10		
COM OFF leakage current ⁽³⁾	I _{COM(OFF)}	V ₊ = 3.6 V, V _{COM} = 1 V, V _{NO} or V _{NC} = 3 V	25°C		1		nA
			Full		10		
COM ON leakage current ⁽³⁾	I _{COM(ON)}	V ₊ = 3.6 V, V _{COM} = 3 V, V _{NO} or V _{NC} = 3 V	25°C		1		nA
			Full		10		
Digital Control Input (IN)							
Input logic high	V _{IH}		Full	2.4		V ₊	V
Input logic low	V _{IL}		Full	0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _{IN} = V ₊ , 0 V	Full			0.01	μA
Dynamic							
Turn-on time ⁽⁴⁾	t _{ON}	See Figure 2	25°C	63	120		ns
			Full		175		
Turn-off time ⁽⁴⁾	t _{OFF}	See Figure 2	25°C	33	80		ns
			Full		120		
Charge injection ⁽⁴⁾	Q _C	C _L = 1 nF, See Figure 1	25°C	–1.5			pC
NO, NC OFF capacitance	C _{NO(OFF)} , C _{NC(OFF)}	f = 1 MHz, See Figure 4	25°C	7.5			pF
COM OFF capacitance	C _{COM(OFF)}	f = 1 MHz, See Figure 4	25°C	7.5			pF
COM ON capacitance	C _{COM(ON)}	f = 1 MHz, See Figure 4	25°C	17			pF
Digital input capacitance	C _I	V _{IN} = V ₊ , 0 V	25°C	1.5			pF
Bandwidth	BW	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	460			MHz
OFF isolation	O _{ISO}	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	–94			dB
Total harmonic distortion	THD	R _L = 50 Ω, C _L = 15 pF, V _{NO} = 1 V _{RMS} , f = 100 kHz	25°C	0.15			%
Supply							
V ₊ supply current	I ₊	V _{IN} = 0 V or V ₊	25°C		0.03		μA
			Full		0.05		

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(2) Typical values are at $T_A = 25^\circ\text{C}$.

(3) Leakage parameters are 100% tested at maximum-rated hot operating temperature, and are ensured by correlation at 25°C .

(4) Specified by design, not production tested

PIN DESCRIPTION⁽¹⁾

PIN NO.				NAME	DESCRIPTION
TS12A4514		TS12A4515			
D, P	SOT-23	D, P	SOT-23		
1	1	1	1	COM	Common
2, 3, 5	–	2, 3, 5	–	N.C.	No connect (not internally connected)
4	5	4	5	V ₊	Power supply
6	4	6	4	IN	Digital control to connect COM to NO or NC
7	3	7	3	GND	Digital ground
8	2	–	–	NO	Normally open
–	–	8	2	NC	Normally closed

(1) NO, NC, and COM pins are identical and interchangeable. Any may be considered as an input or an output; signals pass in both directions.

APPLICATION INFORMATION

Power-Supply Considerations

The TS12A4514/TS12A4515 construction is typical of most CMOS analog switches, except that they have only two supply pins: V_+ and GND. V_+ and GND drive the internal CMOS switches and set their analog voltage limits. Reverse ESD-protection diodes are internally connected between each analog-signal pin and both V_+ and GND. One of these diodes conducts if any analog signal exceeds V_+ or GND.

Virtually all the analog leakage current comes from the ESD diodes to V_+ or GND. Although the ESD diodes on a given signal pin are identical and, therefore, fairly well balanced, they are reverse biased differently. Each is biased by either V_+ or GND and the analog signal. This means their leakages will vary as the signal varies. The difference in the two diode leakages to the V_+ and GND pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of the same or opposite polarity.

There is no connection between the analog-signal paths and V_+ or GND.

V_+ and GND also power the internal logic and logic-level translators. The logic-level translators convert the logic levels to switched V_+ and GND signals to drive the analog signal gates.

Logic-Level Thresholds

The logic-level thresholds are CMOS/TTL compatible when V_+ is 5 V. As V_+ is raised, the level threshold increases slightly. When V_+ reaches 12 V, the level threshold is about 3 V – above the TTL-specified high-level minimum of 2.8 V, but still compatible with CMOS outputs.

CAUTION:

If the user is using the TS12A4514 or TS12A4515 with a V_+ supply of 3 V, then the control input (IN) voltage should not exceed V_+ , otherwise the output levels can exceed 3 V and violate the absolute maximum rating, potentially damaging the device.

High-Frequency Performance

In 50- Ω systems, signal response is reasonably flat up to 250 MHz (see *Typical Operating Characteristics*). Above 20 MHz, the on response has several minor peaks that are highly layout dependent. The problem is not in turning the switch on; it is turning it off. The OFF-state switch acts like a capacitor and passes higher frequencies with less attenuation. At 10 MHz, OFF isolation is about –45 dB in 50- Ω systems, decreasing (approximately 20 dB per decade) as frequency increases. Higher circuit impedances also make OFF isolation decrease. OFF isolation is about 3 dB above that of a bare IC socket, and is due entirely to capacitive coupling.

Test Circuits/Timing Diagrams

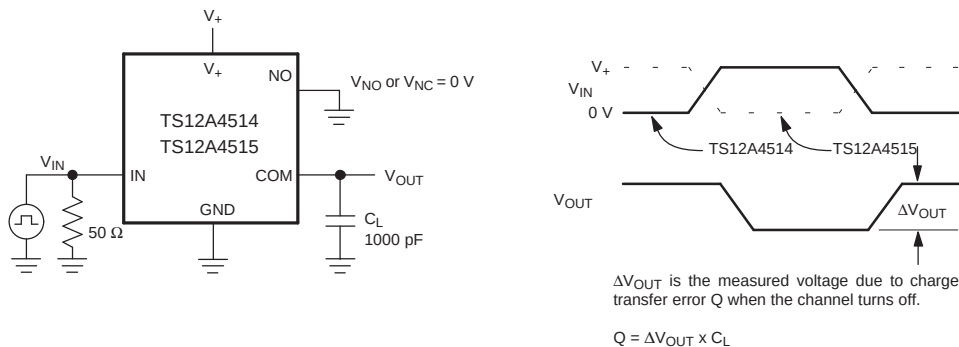


Figure 1. Charge Injection

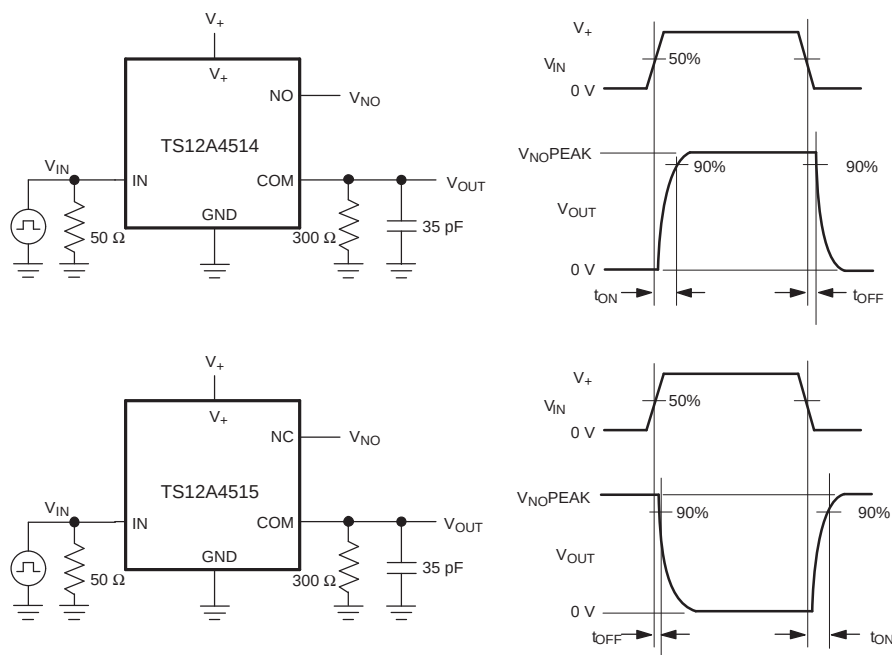


Figure 2. Switching Times

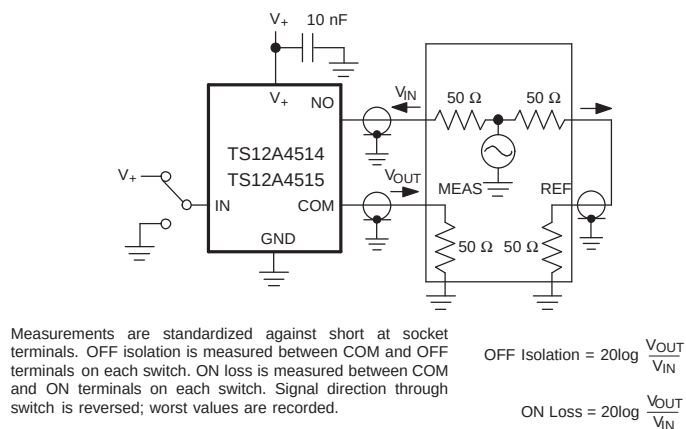


Figure 3. OFF Isolation and ON Loss

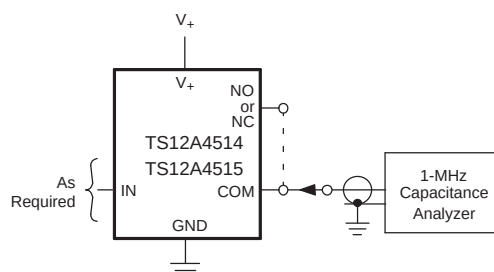


Figure 4. NO, NC, and COM Capacitance

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS12A4514D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD514
TS12A4514D.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD514
TS12A4514D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD514
TS12A4514DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CJE
TS12A4514DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CJE
TS12A4514DBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CJE
TS12A4514DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CJE
TS12A4514DBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CJE
TS12A4514DBVRG4.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CJE
TS12A4514DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD514
TS12A4514DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD514
TS12A4514DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD514
TS12A4514P	NRND	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TS12A4514P
TS12A4514P.A	NRND	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TS12A4514P
TS12A4514P.B	NRND	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TS12A4514P
TS12A4515D	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD515
TS12A4515D.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD515
TS12A4515D.B	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD515
TS12A4515DBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CKE
TS12A4515DBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CKE
TS12A4515DBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CKE
TS12A4515DBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CKE
TS12A4515DBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CKE
TS12A4515DBVRG4.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	9CKE
TS12A4515DR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD515
TS12A4515DR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD515
TS12A4515DR.B	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD515
TS12A4515DRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	YD515
TS12A4515P	NRND	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TS12A4515P

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS12A4515P.A	NRND	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TS12A4515P
TS12A4515P.B	NRND	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TS12A4515P

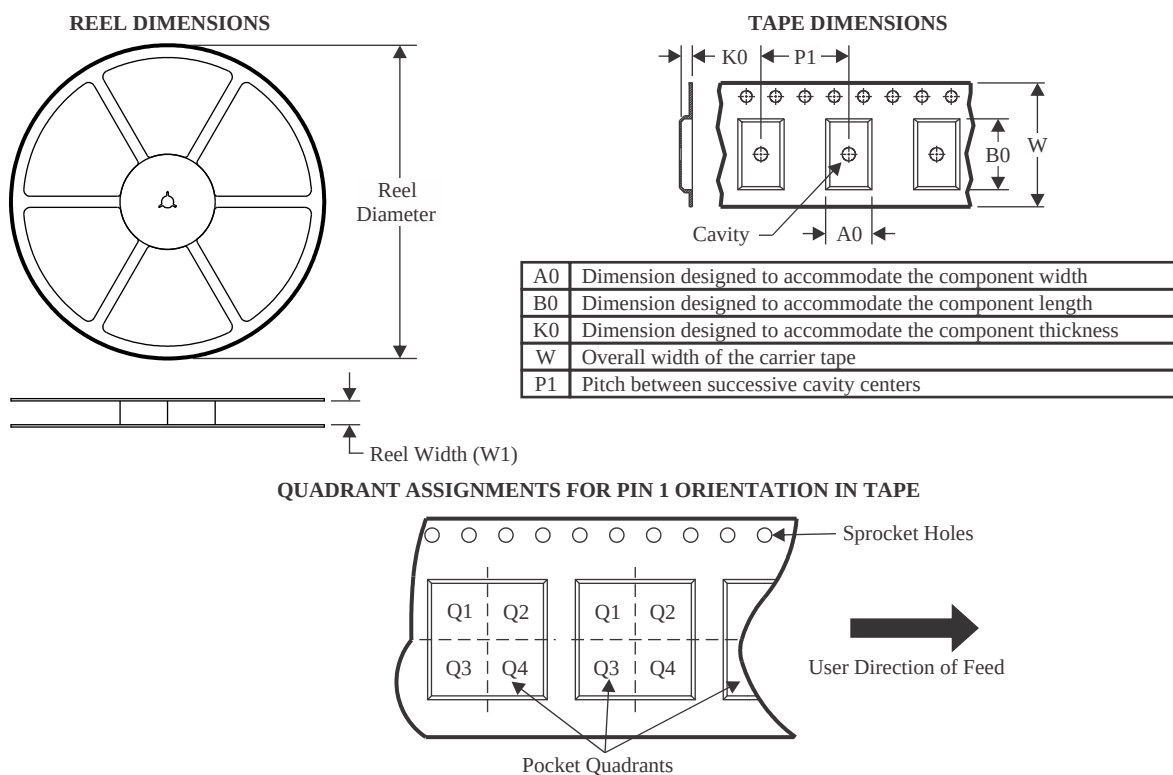
- ⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).
- ⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- ⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- ⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- ⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- ⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

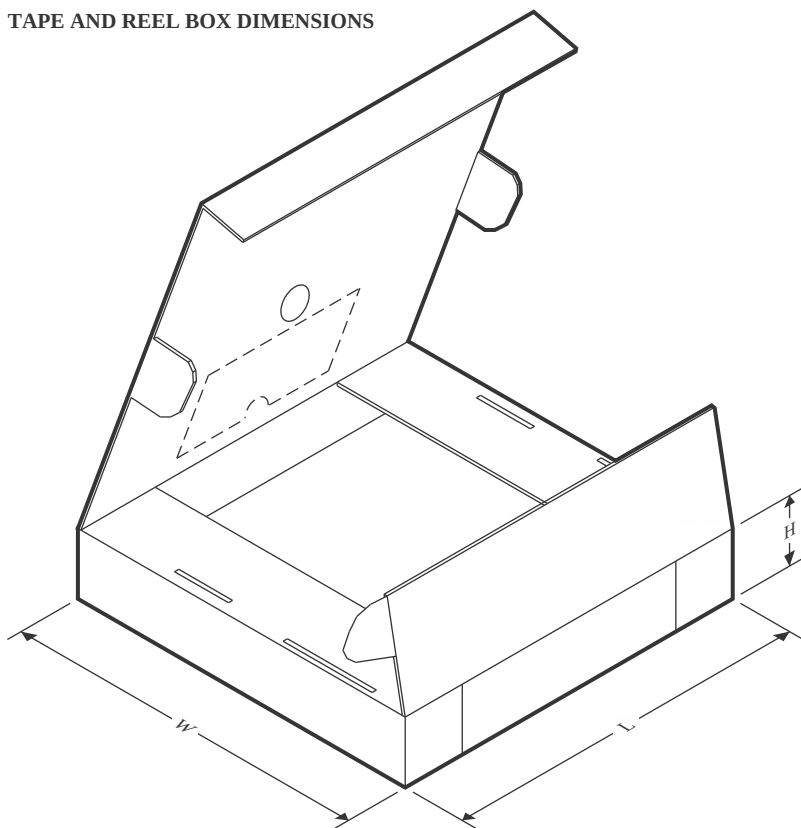
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS12A4514DBVR	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TS12A4514DBVRG4	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TS12A4514DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TS12A4515DBVR	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TS12A4515DBVRG4	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TS12A4515DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

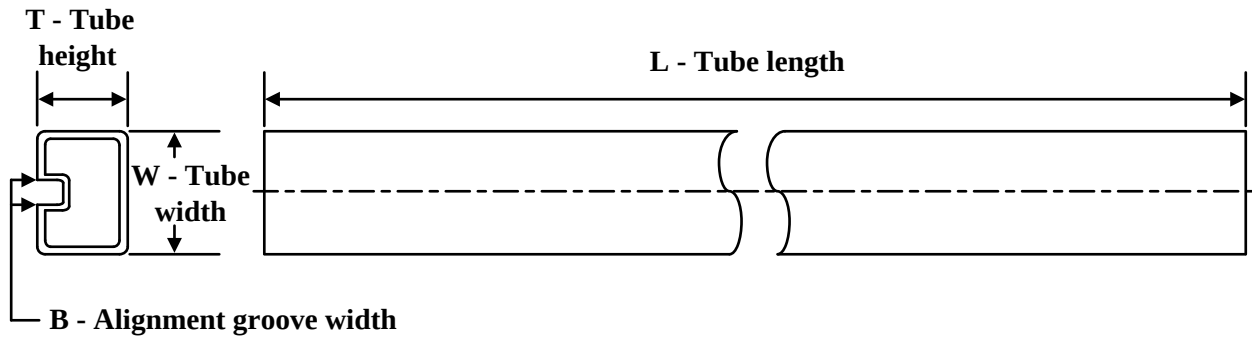
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS12A4514DBVR	SOT-23	DBV	5	3000	200.0	183.0	25.0
TS12A4514DBVRG4	SOT-23	DBV	5	3000	200.0	183.0	25.0
TS12A4514DR	SOIC	D	8	2500	353.0	353.0	32.0
TS12A4515DBVR	SOT-23	DBV	5	3000	200.0	183.0	25.0
TS12A4515DBVRG4	SOT-23	DBV	5	3000	200.0	183.0	25.0
TS12A4515DR	SOIC	D	8	2500	353.0	353.0	32.0

TUBE



*All dimensions are nominal

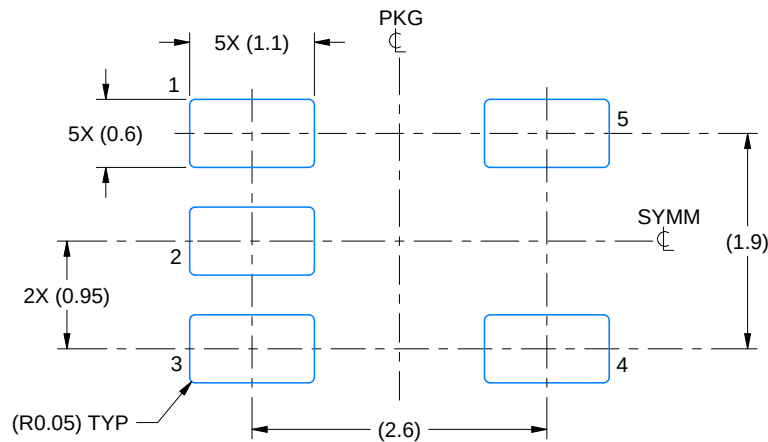
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TS12A4514D	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4514D.A	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4514D.B	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4514P	P	PDIP	8	50	506	13.97	11230	4.32
TS12A4514P.A	P	PDIP	8	50	506	13.97	11230	4.32
TS12A4514P.B	P	PDIP	8	50	506	13.97	11230	4.32
TS12A4515D	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4515D.A	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4515D.B	D	SOIC	8	75	506.6	8	3940	4.32
TS12A4515P	P	PDIP	8	50	506	13.97	11230	4.32
TS12A4515P.A	P	PDIP	8	50	506	13.97	11230	4.32
TS12A4515P.B	P	PDIP	8	50	506	13.97	11230	4.32

EXAMPLE BOARD LAYOUT

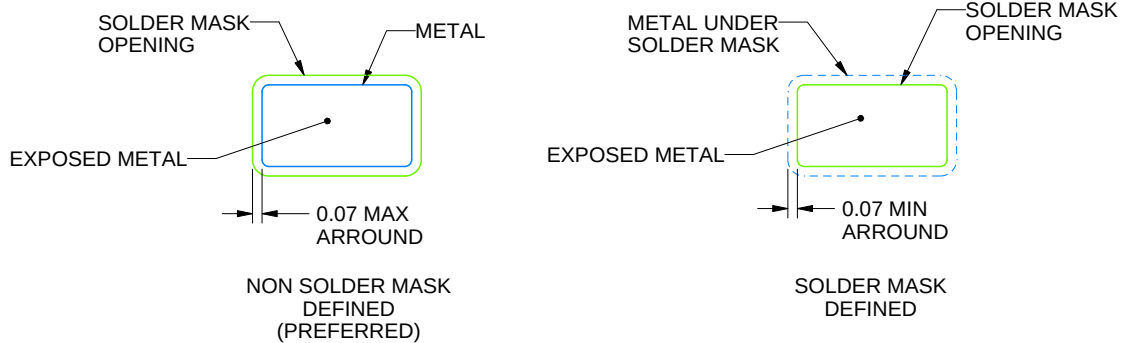
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

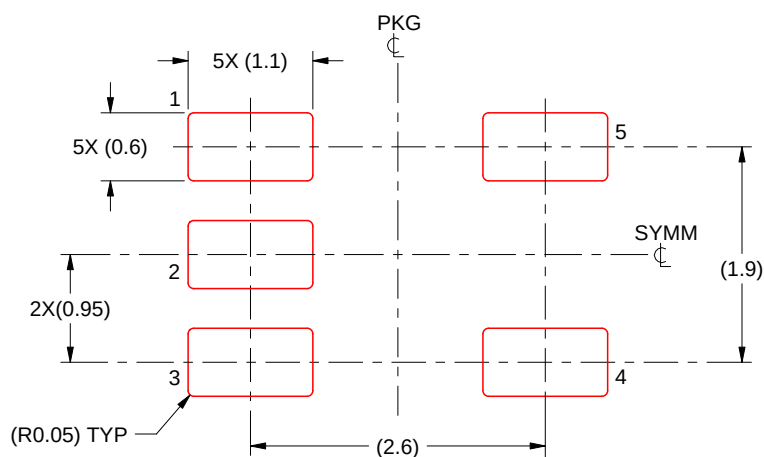
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



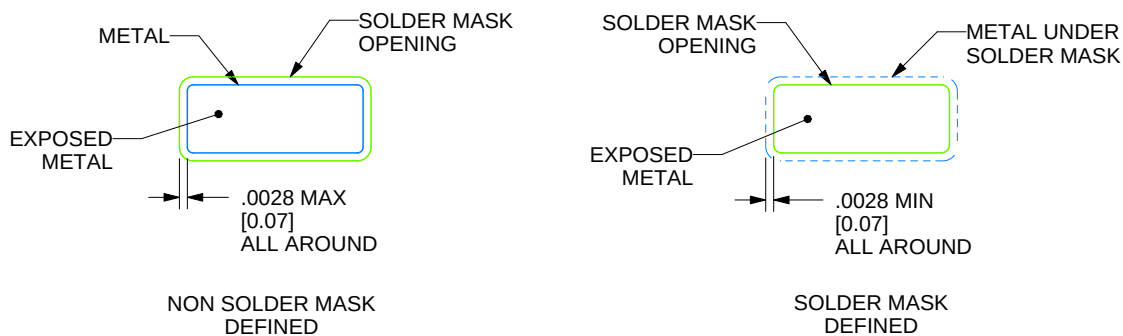
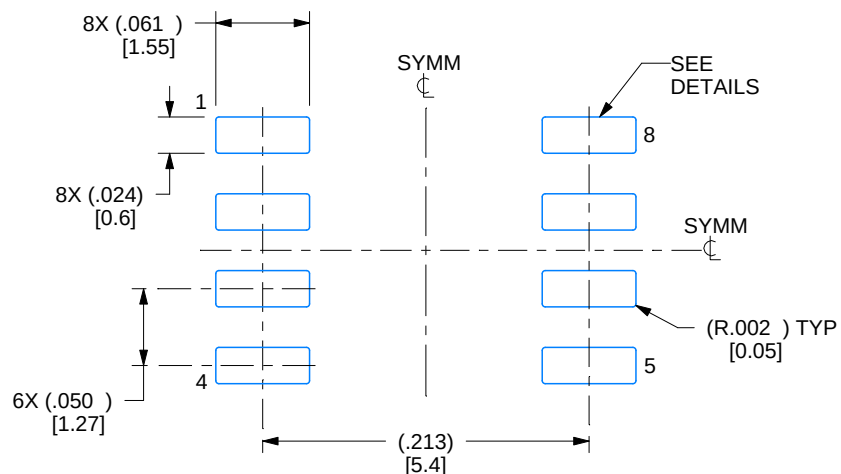
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

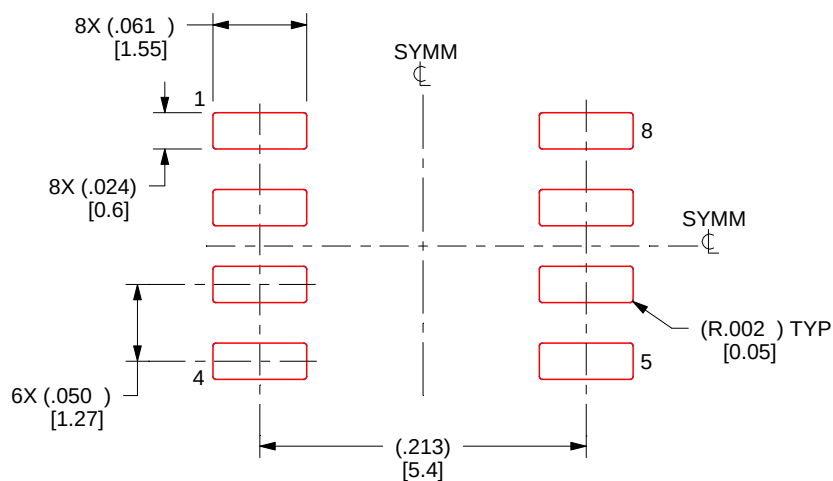
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

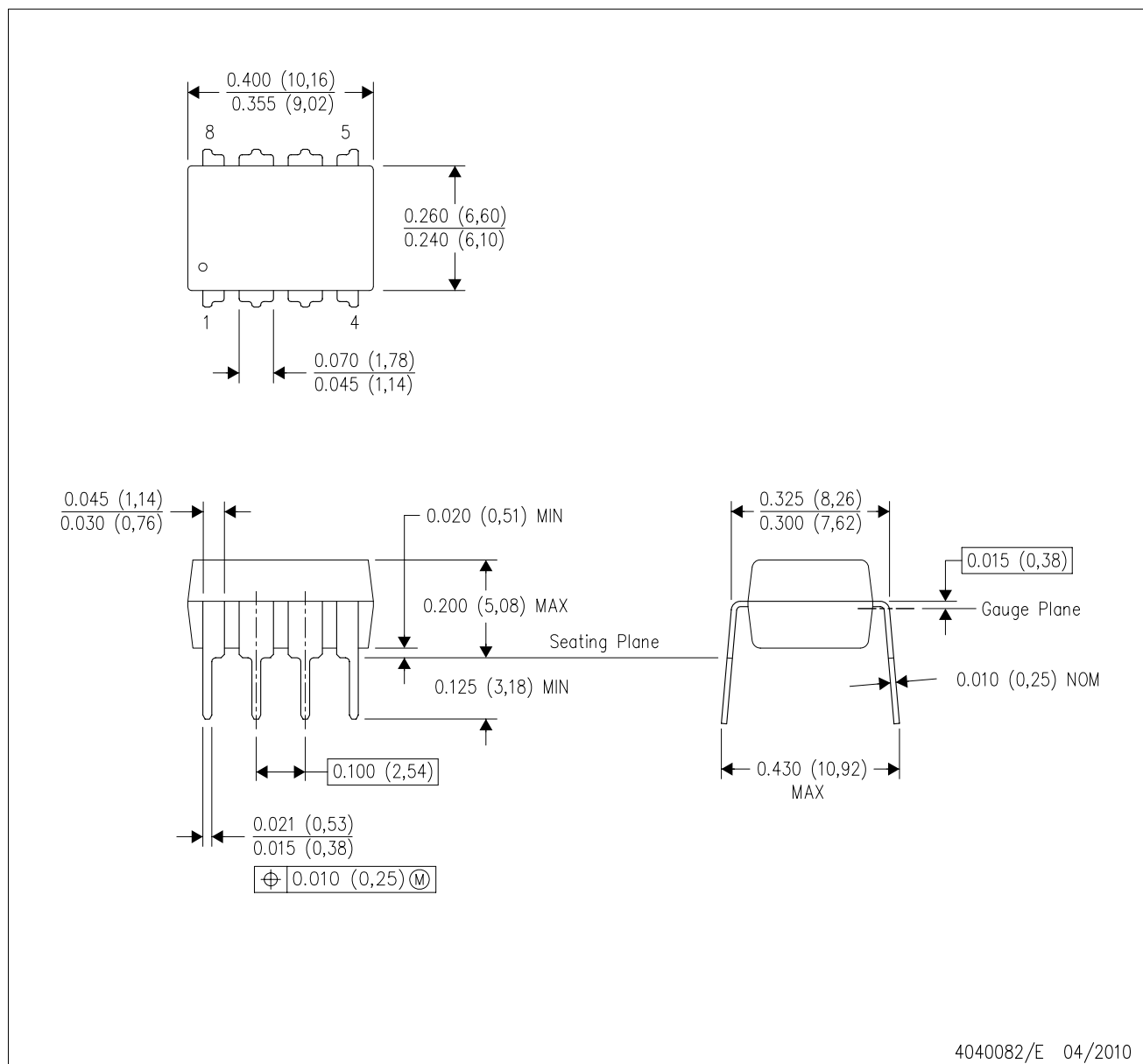
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#), [TI's General Quality Guidelines](#), or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2026, Texas Instruments Incorporated

Last updated 10/2025